# 2SC5482

For Low Frequency Power Amplify Application Silicon NPN Epitaxial Type Micro (Frame type)

#### **DESCRIPTION**

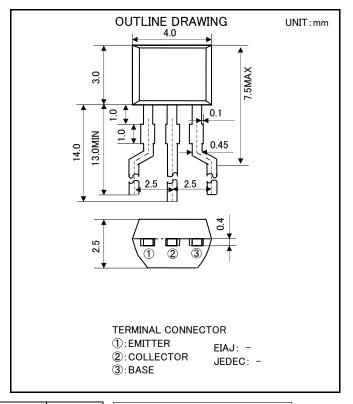
2SC5482 is a silicon NPN epitaxial designed for relay drive or power supply application.

## **FEATURE**

- High collector current IC=1A
- Low VCE(sat)
   VCE(sat)=0.11V typ (@ Ic=500mA,IB=25mA)
- · High voltage VCEO= 60V
- High collector dissipation Pc= 600mW

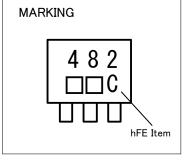
# APPLICATION

Relay drive, power supply for audio equipment, VCR, etc



## MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V <sub>СВО</sub>	Collector to Base voltage	lector to Base voltage 60	
V <sub>EBO</sub>	Emitter to Base voltage	6	٧
Vceo	Collector to Emitter voltage	60	٧
Ісм	Peak collector current	2	Α
Ic	Collector current	1	Α
Pc	Collector dissipation	600	mW
Tj	Junction temperature	+150	°C
Tstg	Storage temperature	−55 <b>~</b> +150	°C



#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

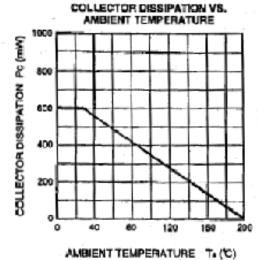
			Limits			
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
V(BR)cBo	C to B break down voltage	$I_{\rm C}$ = 10 $\mu$ A , $I_{\rm E}$ = 0mA	60	-	-	V
V(BR)EBO	E to B break down voltage	$I_{E}=10 \mu A$ , $I_{C}=0 mA$	6	-	-	V
V(BR)ceo	C to E break down voltage	$I_{c}$ =2mA , R <sub>BE</sub> = $\infty$	60	-	-	V
ICBO	Collector cut off current	V $_{\text{CB}}$ = 50V , I $_{\text{E}}$ = 0mA	ı	-	0.2	μΑ
ĪEBO	Emitter cut off current	V $_{\rm EB}$ = 4V , I $_{\rm C}$ = 0mA	ı	-	0.2	μΑ
hFE	DC forward current gain 💥	$V_{CE}$ =4 $V$ , $I_{C}$ = 100mA	55	-	300	_
VCE(sat)	C to E Saturation voltage	$I_{\rm C}$ =500mA , $I_{\rm B}$ = 25mA	ı	0.11	0.3	V
fT	Gain bandwidth product	$V_{CE}$ = 2 $V$ , $I_{E}$ = -10mA	-	120	_	MHz
Cob	Collector output capacitance	V <sub>CB</sub> = 10V , I <sub>E</sub> = 0mA,f=1MHz	-	14	-	pF

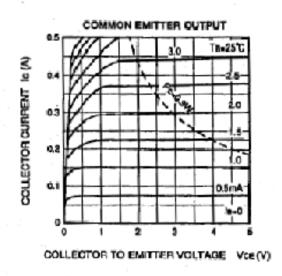
Item	С	D	E
hFE	55 <b>~</b> 110	90~180	150~300

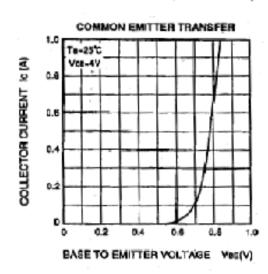
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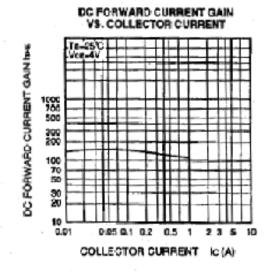
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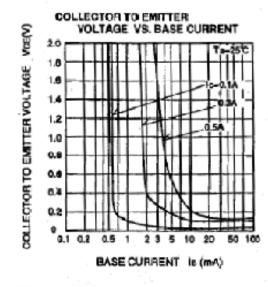
## TYPICAL CHARACTERISTICS

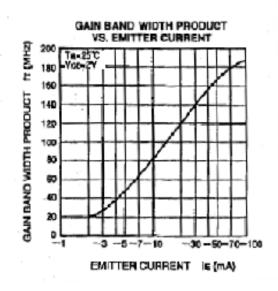








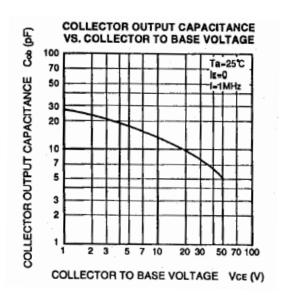




⟨transistor⟩

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6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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